

HIGH-FREQUENCY PIEZOELECTRIC OSCILLATOR

BACKGROUND OF THE INVENTION

Field of the Invention

5 The present invention relates to a high-frequency piezoelectric oscillator, and more particularly, to a high-frequency piezoelectric oscillator having an excellent stabilization characteristics with suppressing unwanted resonance.

10

Description of the Related Art

Conventionally, an odd-order overtone, for example, third, fifth, and seventh-overtone of a vibrator is utilized to obtain oscillation in high frequency. In order to obtain the overtone
15 oscillation, a harmonic selection circuit having high negative resistance at a desired frequency is provided in the oscillation circuit. Figure 22 illustrates one example of a conventional Colpitts type oscillator. A capacitor C11 that becomes a part of a load capacitance of the oscillation circuit is connected
20 between a base and an emitter of a transistor TR11. A parallel resonance circuit consisting of a capacitor C12 and an inductor L11 is connected to the emitter of the transistor TR11. A parallel circuit of a capacitor C13 and an emitter resistor R11 are connected in series to the parallel resonance circuit, and
25 are grounded. A base bias circuit consisting of a resistor RB11 and a resistor RB12 is connected to a base of the transistor TR11. A series circuit of a piezoelectric vibrator (X'tal) and

a capacitor C14 is connected between the base of the transistor TR11 and the ground. A collector of the transistor TR11 and a power supply line (VCC) are connected together.

In the present circuit, an oscillation output cannot be
5 obtained when a desired frequency becomes 600MHz or above. That
is, the resonance frequency of a parallel resonance circuit
comprised of the capacitor C12 and the inductor L11 can be set
to a desired level, however, when the frequency is 600MHz or
above, an impedance of the piezoelectric vibrator lowers due
10 to an interelectrode capacitance C0 of the piezoelectric vibrator.
Accordingly, sufficient negative resistance cannot be generated
in an oscillation loop of the oscillation circuit. To overcome
this difficulty, as shown in Figure 23, the inductor L20 is
inserted in parallel into the piezoelectric vibrator (X'tal).
15 The interelectrode capacitance C0 is canceled by matching the
parallel resonance frequency of the interelectrode capacitance
C0 and the inductor L20 with the oscillation frequency. Since
the parallel circuit of the interelectrode capacitance C0 and
the inductor L20 prevents deterioration of the negative
20 resistance of the oscillation circuit and provides high
selectivity, a high frequency oscillation can be achieved.

In order to make clear a difference between the present
invention and the conventional circuit, the circuit shown in
Figure 23 will be explained in further detail. According to
25 the conventional circuit, capacitors C21 and C22 that form a
part of the negative capacitor are connected between the base
of the transistor TR21 and the ground. The connection point

of the capacitors C21 and C22 is connected to an emitter of the transistor TR21, and is grounded via a resistor R21. A base bias circuit consisting of a resistor RB21 and a resistor RB22 is connected to a base of the transistor TR21. A parallel circuit
5 of the piezoelectric vibrator (X'tal) and the inductor L20 is connected to a capacitor C23, and a series circuit of the parallel circuit and the capacitor is connected between the base of the transistor TR21 and the ground. Further, a collector of the transistor TR21 and the power supply line (Vcc) are connected.

10 Figure 24 illustrates an equivalent circuit model of the conventional circuit shown in Figure 23. In figure 24, the piezoelectric vibrator is indicated by the equivalent circuit comprising a reactance L1, capacitance C1, C0, and resistance R1, and an oscillation circuit is indicated by negative
15 resistance $-R_c$ and reactance X_c . Figure 26 illustrates another equivalent circuit model of the conventional circuit in which a reactance of a parallel resonance circuit comprised of the capacitance C0 and inductance L0 shown in Figure 24 is presented as X_0 .

20 Expressions for an oscillation condition are as follows.

$$X_c = \frac{1}{\omega C_c}, \dots X_0 = \frac{1}{\omega C_0 \left(\frac{\omega_0^2}{\omega^2} - 1 \right)}, \dots C_\alpha = C_0 \left(1 - \frac{\omega_0^2}{\omega^2} \right), \dots C_L = -\frac{1}{\omega X_L}, \dots (1)$$

$$\dots X_c = \frac{1}{\omega C_c}, \dots X_0 = \frac{1}{\omega C_0 \left(\frac{\omega_0^2}{\omega^2} - 1 \right)}$$

$$\dots R_L = \frac{-R_c X_0^2}{R_c^2 + (X_0 - X_c)^2}, \dots X_L = \frac{X_0 \{ R_c^2 - X_c (X_0 - X_c) \}}{R_c^2 + (X_0 - X_c)^2}$$

$$\dots (2)$$

$$\dots R_1 + R_L = 0$$

$$\omega L_1 + \frac{1}{\omega C_1} + X_L = 0 \dots (3)$$

Figure 25 illustrates a result of carrying out a simulation about characteristics of negative resistance R_c and capacitance C_c of a conventional Colpitts oscillation circuit. The axis of ordinates represents negative resistance, and the axis of abscissas represents frequency. From Figure 25, it is clear that negative resistance does not occur when the frequency is about 400MHz or below. However, negative resistance considerably occurs over 400MHz frequencies. It can be seen that negative resistance occurs sufficiently at 2GHz.

Impedance Z_L is obtained and Exps. (4) and (5) are obtained based on the equivalent circuit shown in Figure 26. An Exp. (6) that shows a relationship between the resistance R_L and the reactance X_L shown in Figure 27 is obtained from Z_L .

$$Z_L = \frac{jX_0(-R_c - jX_c)}{-R_c - jX_c + jX_0} \dots X_c = \frac{1}{\omega C_c} \dots X_0 = \frac{1}{\omega C_0 \left(\frac{\omega_0^2}{\omega^2} - 1 \right)} \dots (4)$$

$$\begin{aligned} &= \frac{X_0(X_0 - jR_c)}{-R_c + j(X_0 - X_c)} = \frac{X_0(X_c - jR_c)(-R_c - j(X_0 - X_c))}{R_c^2 + (X_0 - X_c)^2} = \frac{-X_0(X_c - jR_c)(R_c + j(X_0 - X_c))}{R_c^2 + (X_0 - X_c)^2} \\ &= \frac{-X_0[X_c R_c + R_c(X_0 - X_c) + j\{X_c(X_0 - X_c) - R_c^2\}]}{R_c^2 + (X_0 - X_c)^2} \\ &= \frac{-X_0[R_c X_0 + j\{X_c(X_0 - X_c) - R_c^2\}]}{R_c^2 + (X_0 - X_c)^2} \dots (5) \end{aligned}$$

$$\begin{aligned} R_L &= \frac{-R_c X_0^2}{R_c^2 + (X_0 - X_c)^2} \dots X_L = \frac{-X_0\{X_c(X_0 - X_c) - R_c^2\}}{R_c^2 + (X_0 - X_c)^2} = \frac{X_0\{R_c^2 - X_c(X_0 - X_c)\}}{R_c^2 + (X_0 - X_c)^2} \\ R_L &= \frac{-R_c X_0^2}{R_c^2 + S^2} \dots X_L = \frac{X_0\{R_c^2 - X_c S\}}{R_c^2 + S^2} \dots S = X_0 - X_c \dots (6) \end{aligned}$$

Figure 28 illustrates characteristics of a load resistance RL shown in Figure 27. The axis of ordinates represents negative resistance Rc, and the axis of abscissas represents frequency. From Figure 28, it is clear that, a largest negative resistance Rc is -300Ω at 600MHz. The circuit shown in Figure 27 constitutes an unwanted oscillation loop shown in Figure 30, and the circuit oscillates in the resonance frequency of reactance X0 + Xc = 0. The oscillation loop includes negative resistance -Rc, and has no factor of anti-negative resistance. Therefore, oscillation occurs very easily. The Exp. (7) represents a frequency condition fω = 0. Figure 31 shows a frequency relationship.

$$\dots\dots F = X_0 + X_c = \frac{1}{\omega C_0 \left(\frac{\omega_0^2}{\omega} - 1 \right)} - \frac{1}{\omega C_c} = 0 \dots\dots (7)$$

Figure 31 is a graph of unwanted resonance frequency when $C_c = 3, 5, 10, 30, \text{ and } 100 \text{ pF}$ respectively in a condition that $C_0 = 3 \text{ pF}$, the parallel resonance frequency is $f_0 = 600 \text{ MHz}$, and the circuit negative resistance $R_c = -100 \Omega$. The frequency when $X_0 - X_c = 0$ on each characteristic curve is unwanted resonance frequency.

Figure 32 illustrates a relationship between unwanted resonance frequency and circuit capacitance. The axis of ordinates represents unwanted resonance frequency, and the axis of abscissas represents circuit capacitance. In the present circuit, X_0 works as inductor at a low frequency side of the parallel resonance frequency, and this has a possibility of bringing about unwanted oscillation when the inductor is connected with the circuit capacitance at the circuit side. For example, when the parallel resonance frequency of the interelectrode capacitance C_0 and the inductor L_0 is set to 600 MHz and also when $C_0 = 3 \text{ pF}$, the parallel resonance frequency is 590 MHz when the circuit capacitance $C_c = 1 \text{ pF}$, and the parallel resonance frequency is 100 MHz when the circuit capacitance $C_c = 100 \text{ pF}$. However, from the above result of the simulation of negative resistance, there is a possibility that oscillation occurs at an unwanted resonance point in the vicinity of the parallel resonance frequency. Further, when an extension coil L_1 is used to enlarge a variable range in the oscillation circuit loop,

unwanted oscillation occurs in a wide band in connection with a large capacitance generated in the vicinity of the resonance point as shown in Figure 29.

According to the conventional high-frequency oscillation circuit shown in Figure 23, unwanted oscillation contributed by the oscillation circuit and the inductor L20 as explained above is easily occurred. Further more, when an extension coil for expanding a frequency variable range is inserted into the oscillation loop, unwanted oscillation occurs easily at the parallel resonance frequency defined by the interelectrode capacitance C0 and the inductor L20. Further, a high negative resistance cannot be obtained easily by the conventional oscillation circuits explained the above. Therefore, there are some report regarding experimental results of the high frequency oscillation circuit, but there is substantially no success in practical applications.

SUMMARY OF THE INVENTION

The present invention has been made in the light of the above problems. It is an object of the present invention to provide a high-frequency piezoelectric oscillator having high stability characteristics, and the oscillator suppress unwanted oscillation by decreasing the interelectrode capacitance C0.

It is another object of the present invention to provide a high-frequency piezoelectric oscillator that can prevent the occurrence of unwanted oscillation due to the use of an extension coil when the extension coil is provided in an oscillation loop

in order to enlarge the oscillation frequency variable range.

The present invention has been made to solve the above problems. According to a first aspect of the present invention, there is provided a high-frequency piezoelectric oscillator including a piezoelectric oscillator having a piezoelectric element that is excited in a predetermined frequency, and an oscillation amplifier that oscillates the piezoelectric element by flowing current to the piezoelectric element, wherein an inductor and a resistor are insertion connected in parallel respectively to the piezoelectric oscillator of the high-frequency piezoelectric oscillator, and resonance frequency of a parallel resonance circuit consisting of the inductor and the resistor is set to the vicinity of the oscillation frequency of the high-frequency piezoelectric oscillator thereby to increase negative resistance applied to a series arm of the piezoelectric element and suppress unwanted oscillation due to the inductor.

According to a second aspect of the present invention, there is provided a high-frequency piezoelectric oscillator including a piezoelectric oscillator having a piezoelectric element that is excited in a predetermined frequency, and an oscillation amplifier that oscillates the piezoelectric element by flowing current to the piezoelectric element, wherein a circuit having an inductor and a variable capacitance diode connected in series and a resistor are insertion connected in parallel respectively to the piezoelectric oscillator of the high-frequency piezoelectric oscillator, resonance frequency

of a parallel resonance circuit consisting of the inductor and the resistor is set to the vicinity of the oscillation frequency of the high-frequency piezoelectric oscillator, thereby to increase negative resistance applied to a series arm of the piezoelectric element and externally fine adjust the capacitance of the variable capacitance diode so as to optimize oscillation and make it possible to control frequency.

According to a third aspect of the present invention, there is provided a high-frequency piezoelectric oscillator including a piezoelectric oscillator having a piezoelectric element that is excited in a predetermined frequency, and an oscillation amplifier that oscillates the piezoelectric element by flowing current to the piezoelectric element, wherein a first inductor and a resistor are connected in parallel respectively to the piezoelectric oscillator of the high-frequency piezoelectric oscillator, the connection point is grounded via a circuit having a second inductor and a variable capacitance diode connected in series, and resonance frequency of a parallel resonance circuit consisting of the first inductor and the resistor is set to the vicinity of the resonance frequency of the high-frequency piezoelectric oscillator, thereby to increase negative resistance applied to a series arm of the piezoelectric element and externally fine adjust the capacitance of the variable capacitance diode so as to optimize oscillation and make it possible to control frequency.

According to a fourth aspect of the present invention, there is provided a high-frequency piezoelectric oscillator

according to any one of the first to third aspects, wherein the following relationships are fulfilled:

$$R_1 + R_L = 0$$

$$\omega L_1 + \frac{1}{\omega C_1} + X_L = 0 \quad \dots\dots\dots (I)$$

5 when

$$X_0 = \frac{1}{\omega C_0} \times \frac{1}{\left(1 - \frac{\omega_0^2}{\omega^2}\right)} = \frac{1}{\omega C_0} \times \frac{1}{\left(\frac{\omega^2}{\omega_0^2} - 1\right)}$$

10

$$z_0 = \frac{R_0 X_0^2}{R_0^2 + X_0^2} + j \frac{X_0 R_0^2}{R_0^2 + X_0^2}$$

$$r_a = \frac{R_0 X_0^2}{R_0^2 + X_0^2} \dots\dots\dots X_a = \frac{X_0 R_0^2}{R_0^2 + X_0^2}$$

15

$$Z_L = \frac{-r_a R_c + X_a X_c - j(X_a R_c + X_c r_a)}{r_a - R_c + j(X_a - X_c)}$$

$$A = r_a - R_c \dots\dots B = X_a - X_c \dots\dots C = R_c^2 + X_c^2 \dots\dots D = r_a^2 + X_a^2$$

$$R_L = \frac{r_a \times C - R_c \times D}{A^2 + B^2} \dots\dots\dots X_L = \frac{X_c \times D - X_a \times C}{A^2 + B^2}$$

20

where $-R_c$ represents the negative resistance, C_c represents circuit capacitance, C_0 represents interelectrode capacitance of the piezoelectric oscillator, X_0 represents reactance of a parallel circuit of the inductor L_0 , R_0 represents

resistance of the resistor, $-X_c$ represents circuit capacitance of the circuit, r_α represents parallel connection resistance of the X_0 and R_0 , X_α represents reactance, R_L represents negative resistance of the series arm of the oscillator, X_L represents reactance, and (I) represents an oscillation condition.

According to a fifth aspect of the present invention, there is provided a high-frequency piezoelectric oscillator according to the first aspect wherein

$\omega_1 < \omega_T < \omega_2$ (Exp. 1) is fulfilled, when

ω_T represents unwanted resonance non-angular frequency, C_0 represents interelectrode capacitance of the oscillator, R_c represents an absolute value of negative resistance of an additional resistor and an oscillation circuit that are connected in parallel to the C_0 , L_0 represents an additional inductor that is connected in parallel to the C_0 , and ω_0 represents parallel resonance angular frequency of the C_0 and L_0 , where

(Exp. 2) to (Exp. 4) are fulfilled

$$\omega_1 = \sqrt{\omega_0^2 + \frac{K - \sqrt{K(K + 4\omega_0^2)}}{2}}, \dots, \omega_2 = \sqrt{\omega_0^2 + \frac{K + \sqrt{K(K + 4\omega_0^2)}}{2}}, \dots, K = \frac{M}{C_0^2 R_0^2}, \dots, M = \frac{R_0}{R_c} - 1$$

$M > 0, R_0 > R_c \dots \dots \dots$ (Exp. 2)

$$\dots T = 2 \dots 1 = \sqrt{\frac{K^2}{4 \dots 2} + K} = \frac{0}{2Q_0} \sqrt{M(4Q_0 + M)} \dots \dots \dots \text{(Exp. 3)}$$

$\dots T$: Unwanted resonance non-angular bandwidth

$$\dots Q = \frac{R_0}{L_0} = \dots C_0 R_0 \dots \dots \dots \text{(Exp. 4)}$$

the (Exp. 1) represents unwanted resonance non-angular bandwidth, (Exp. 2) represents a condition for fulfilling the (Exp. 1), and (Exp. 3) represents an unwanted band,

5 (Exp. 5) is fulfilled, where

$$\begin{aligned} \dots\dots\dots R_L &= \frac{r \times C - R_c \times D}{A^2 + B^2} \dots\dots\dots X_L = \frac{X \times C - X_c \times D}{A^2 + B^2} \dots\dots\dots (\text{Exp. 5}) \\ \dots\dots\dots r &= \frac{R_0 X_0^2}{R_0^2 + X_0^2}, \dots\dots\dots X = \frac{X_0 R_0^2}{R_0^2 + X_0^2}, \dots\dots\dots X_0 = \frac{1}{C_0 \left(\frac{2}{\frac{0}{2}} - 1 \right)}, \dots\dots\dots X_c = \frac{1}{C_c} \\ \dots\dots\dots A &= r - R_c, \dots\dots\dots B = X - X_c, \dots\dots\dots C = R_c^2 + X_c^2, \dots\dots\dots D = r^2 + X^2 \end{aligned}$$

Q represents parallel resonance angular frequency which is a ratio of a real number to reactance shown by the ω_0 in the (Exp. 4), RL represents the negative resistance for oscillating the series arm consisting of L1/C1/R0 of the oscillator, XL represents reactance, Cc represents circuit capacitance of the oscillation circuit, and ω represents oscillation angular frequency, and

10

(Exp. 5) represents negative resistance and load capacitance for oscillating a series arm consisting of L1/C1/R0 of the oscillator.

15

According to a sixth aspect of the present invention, there is provided a high-frequency piezoelectric oscillator according to any one of the first, second, third and fourth aspects, wherein the resistance within a range according to the fifth aspect is

20

organized within an inductor, and the inductor having the

inductor and the resistor integrated together is connected in parallel to the interelectrode capacitance C_0 of the oscillator.

BRIEF DESCRIPTION OF THE DRAWINGS

5 Figure 1 is a configuration diagram of a first high-frequency piezoelectric oscillator according to the present invention;

 Figure 2 is a configuration diagram of an equivalent circuit 1 of the first high-frequency piezoelectric oscillator
10 according to the present invention;

 Figure 3 is a configuration diagram of an equivalent circuit 2 of the first high-frequency piezoelectric oscillator according to the present invention;

 Figure 4 is a configuration diagram of an equivalent
15 circuit 3 of the first high-frequency piezoelectric oscillator according to the present invention;

 Figure 5 is a configuration diagram of an equivalent circuit 4 of the first high-frequency piezoelectric oscillator according to the present invention;

20 Figure 6 illustrates a relationship between load resistance R_L , circuit negative resistance R_c , oscillator parallel capacitance, and parallel additional resistance R_0 to an inductance L_0 according to the present invention;

 Figure 7 illustrates a relationship between the parallel
25 additional resistance R_0 and the load resistance R_L connected to a series arm according to the present invention;

 Figure 8 illustrates a relationship between load

capacitance CL and frequency;

Figure 9 is a configuration diagram of an equivalent circuit that shows unwanted oscillation of the first high-frequency piezoelectric oscillator according to the present invention;

Figure 10 illustrates an unwanted oscillation region of the first high-frequency piezoelectric oscillator according to the present invention;

Figure 11 is a graph of unwanted resonance frequency according to the present invention;

Figure 12 illustrates a relationship between unwanted resonance frequency and circuit capacitance;

Figure 13 is a circuit diagram of a high-frequency piezoelectric oscillator according to the first embodiment of the present invention;

Figure 14 is a waveform diagram of an oscillation circuit according to the present invention;

Figure 15 illustrates power supply variation characteristics of the oscillation circuit according to the present invention;

Figure 16 illustrates a result of a simulation carried out using the oscillation circuit according to the present invention;

Figure 17 is a circuit diagram of a high-frequency piezoelectric oscillator according to the second embodiment of the present invention;

Figure 18 is a circuit diagram of a high-frequency

piezoelectric oscillator according to the third embodiment of the present invention;

Figure 19 illustrates a relationship between additional resistance R_0 , load resistance R_L , and unwanted resonance frequency when oscillation frequency is 622MHz according to the present invention;

Figure 20 illustrates a relationship between Q , negative resistance R_L , and unwanted resonance bandwidth, where the Q changes by changing the additional resistance R_0 in the parallel resonance of $C_0/L_0/R_0$ when the parallel resonance frequency $f_0 = 600\text{MHz}$, according to the present invention;

Figure 21 illustrates a relationship between negative resistance of a series arm and unwanted resonance bandwidth when the additional resistance is fixed to $R_0 = 200\Omega$ and when the negative resistance of the circuit is variable;

Figure 22 illustrates one example of a conventional Colpitts type oscillator;

Figure 23 illustrates another example of a conventional Colpitts type oscillator;

Figure 24 illustrates an equivalent circuit model of a conventional circuit;

Figure 25 illustrates a result of carrying out a simulation about characteristics of negative resistance R_c and circuit capacitance C_c of a representative Colpitts oscillation circuit;

Figure 26 illustrates X_0 that represents reactance of a parallel resonance circuit of the parallel capacitance C_0 and the inductor L_0 of the oscillator of the equivalent circuit shown

in Figure 24;

Figure 27 illustrates X_0 that represents reactance of a parallel resonance circuit of the parallel capacitance C_0 and the inductor L_0 of the oscillator of the equivalent circuit shown
5 in Figure 24;

Figure 28 illustrates characteristics of series arm load resistance R_L based on the diagram shown in Figure 27;

Figure 29 illustrates a relationship between series arm load capacitance and frequency based on the diagram shown in
10 Figure 27;

Figure 30 illustrates an unwanted resonance loop;

Figure 31 illustrates unwanted resonance frequency; and

Figure 32 illustrates a relationship between unwanted resonance frequency and circuit capacitance.

15

DETAILED DESCRIPTIONS

High-frequency piezoelectric oscillator according to embodiments of the present invention will be explained in detail below with reference to the accompanying drawings. Unless
20 specified otherwise, the scope of the present invention is not limited to constituent elements, kinds, combinations, shapes, and relative arrangements described in the embodiments. These show only examples.

Figure 1 is a configuration diagram of a first
25 high-frequency piezoelectric oscillator according to the present invention. In this high-frequency piezoelectric oscillator, a series circuit of capacitors C_1 and C_2 as a part

of a load capacitance are connected between a base of a transistor TR1 and the ground. The connection point of the capacitors C1 and C2 is connected to an emitter of a transistor TR21, and is grounded via a resistor R1. A base bias circuit consisting of
5 a resistor RB1 and a resistor RB2 is connected to the base of the transistor TR1. A parallel circuit of a piezoelectric vibrator (X'tal), an inductor L0, and a resistor R0 is connected to a capacitor C3, and the parallel circuit is connected to the base of the transistor TR1, and the capacitor is connected to
10 the ground. A collector of the transistor TR1 and a power supply line (Vcc) are connected together.

Figure 2 is a configuration diagram of an equivalent circuit 1 of the first high-frequency piezoelectric oscillator, shown in Figure 1, according to the present invention. C0
15 represents interelectrode capacitance of the piezoelectric vibrator (X'tal), L1 represents an inductor, C1 represents capacitance, R1 represents resistance, $-R_c$ represents negative resistance of an oscillation circuit, and Cc represents circuit capacitance. Figure 3 is a configuration diagram of an
20 equivalent circuit 2, where X0 represents reactance of a parallel circuit of the interelectrode capacitance C0 of the piezoelectric vibrator (X'tal) and an inductor L0, and $-X_c$ represents circuit capacitance of the circuit. In this equivalent circuit 2, the reactance X0 and a resistance R0 is connected in parallel. Figure
25 4 is a configuration diagram of an equivalent circuit 3, where the parallel circuit of the reactance X0 and the resistance R0 in Figure 3 is converted to a series circuit of a resistance

ra and reactance Xα. In this Figure 3, -Rc represents negative resistance of the oscillation circuit, and Xc represents circuit capacitance. Figure 5 shows an equivalent circuit consisting of the negative resistance RL and XL that are converted from the series circuit connected to the piezoelectric vibrator (X'tal) (hereinafter, the series circuit connected to the piezoelectric vibrator is referred to as "series arm"). Exp. (8) shows an oscillation condition of the equivalent circuit shown in Figure 3.

10

$$\begin{aligned} \dots\dots R_1 + R_L &= 0 \\ \omega L_1 + \frac{1}{\omega C_1} + X_L &= 0 \dots\dots\dots (8) \end{aligned}$$

The reactance X0 shown in Figure 3 is obtained, and Exp. (9) is obtained.

$$\begin{aligned} jX_0 &= \frac{\frac{L_0}{C_0}}{j\omega L_0 + \frac{1}{j\omega C_0}}, \dots\dots\dots \omega_0^2 = \frac{1}{L_0 C_0} \dots\dots\dots \omega_0 = \frac{1}{\sqrt{L_0 C_0}} \\ \dots\dots\dots &= \frac{L_0}{C_0} \times \frac{1}{j\omega L_0 \left(1 - \frac{1}{\omega^2 C_0 L_0}\right)} = \frac{1}{j\omega C_0} \times \frac{1}{\left(1 - \frac{1}{\omega^2 C_0 L_0}\right)} = -j \frac{1}{\omega C_0} \times \frac{1}{\left(1 - \frac{1}{\omega^2 C_0 L_0}\right)} \\ \dots\dots X_0 &= -\frac{1}{\omega C_0} \times \frac{1}{\left(1 - \frac{\omega_0^2}{\omega^2}\right)} = \frac{1}{\omega C_0} \times \frac{1}{\left(\frac{\omega_0^2}{\omega^2} - 1\right)} \dots\dots\dots (9) \end{aligned}$$

15

The resistance ra and the reactance Xα shown in Figure

4 are obtained, and Exp. (10) is obtained. The resistance R_L and the reactance X_L shown in Figure 5 are obtained, and Exp. (11) is obtained.

$$\begin{aligned} \dots\dots\dots z_0 &= \frac{jX_0 \times R_0}{R_0 + jX_0} = \frac{jX_0 \times R_0 (R_0 - jX_0)}{R_0^2 + X_0^2} = \frac{X_0 \times R_0 (X_0 + jR_0)}{R_0^2 + X_0^2} = \frac{R_0 X_0^2}{R_0^2 + X_0^2} + j \frac{X_0 R_0^2}{R_0^2 + X_0^2} \\ \dots\dots\dots r_\alpha &= \frac{R_0 X_0^2}{R_0^2 + X_0^2}, \dots\dots\dots X_\alpha = \frac{X_0 R_0^2}{R_0^2 + X_0^2} \dots\dots\dots (10) \end{aligned}$$

$$\begin{aligned} \dots\dots\dots Z_L &= \frac{(r_\alpha + jX_\alpha)(-R_c - jX_c)}{r_\alpha + jX_\alpha - R_c - jX_c} \\ \dots\dots\dots &= \frac{-r_\alpha R_c + X_\alpha X_c - j(X_\alpha R_c + X_c r_\alpha)}{r_\alpha - R_c + j(X_\alpha - X_c)}, \dots\dots\dots \\ \dots\dots\dots A &= r_\alpha - R_c, \dots\dots\dots B = X_\alpha - X_c, \dots\dots\dots C = R_c^2 + X_c^2, \dots\dots\dots D = r_\alpha^2 + X_\alpha^2 \\ \dots\dots\dots R_L &= \frac{r_\alpha \times C - R_c \times D}{A^2 + B^2}, \dots\dots\dots X_L = \frac{X_c \times D - X_\alpha \times C}{A^2 + B^2} \dots\dots\dots (11) \end{aligned}$$

5 Figure 6 illustrates a relationship between the resistance R_0 and the load resistance R_L , and a relationship between the resistance R_0 and the capacitance C_L obtained from the Exps. (10) and (11). The left side of the axis of an ordinate represents the load resistance R_L , the right side of the axis of an ordinate
10 represents the capacitance C_L , and the axis of an abscissa represents the parallel resistance R_0 . From Figure 6, it is clear from the variation of the load resistance R_L that connects to the series arm, there is an optimum value for the parallel resistance R_0 . In other words, it is clear that the load
15 resistance R_L is stable when the parallel resistance R_0 is

approximately 200Ω . The parallel resonance frequency of the L0 and C0 is 600MHz, the oscillation frequency is 620MHz, and C0 = 3pF.

Figure 7 illustrates a relationship between the load resistance RL connected to the series arm and the oscillation frequency depending on the parallel resistance R0 (200 Ω , 300 Ω , and 600 Ω). The ordinate represents the load resistance RL, and the abscissa represents frequency. From Figure 7, it is clear that when the parallel resistance R0 increases, the load resistance RL of the series arm. The parallel resonance frequency of the L0 and C0 is 600MHz, C0 = 3pF, and Ce = 30pF.

Figure 8 illustrates a relationship between the load capacitance CL and frequency. The ordinate represents the load capacitance CL, and the abscissa represents frequency. From Figure 8, it is clear that the circuit capacitance CL is capacitive at 580MHz or above when the parallel resonance frequency f0 defined by the L0 and Co is 600MHz.

Figure 9 is an equivalent circuit of the present invention shown in Figure 1 under the condition of an unwanted oscillation state. Exp. (12) represents a condition that the circuit does not oscillate. Exp. (13) represents a condition that the circuit can oscillate. Exp. (14) represents an oscillation frequency condition.

$$r_a - R_c > 0 \dots\dots\dots (12)$$

$$r_a - R_c < 0 \dots\dots\dots (13)$$

$$X_a - X_c = 0 \dots\dots\dots (14)$$

Figure 10 illustrates an unwanted oscillation region of the circuit, shown in Figure 1, according to the present invention. The ordinate represents $r_\alpha - R_c$, and the abscissa represents frequency. From Figure 10, it is clear that in the frequency region from about 480MHz to 750MHz, the series resistance r_α that occurs based on the resistance R_0 parallel connected to the oscillator becomes larger than the negative resistance R_c that occurs from the circuit. As this state fulfills the Exp. (12), this region becomes an oscillation impossible region 3. As is clear from the characteristics curves 5 and 6, this region is constant regardless of R_0 . In other regions 1 and 2, oscillation is possible. However, Q_r due to the inductor L_0 and the resistance R_0 becomes as shown in Figure 10.

Figure 11 represents a relationship between unwanted resonance frequency f_t and resistance $X_\alpha - X_c$ when $C_c = 1, 3, 5, 10, 30,$ and 100 pF respectively in a condition that $C_0 = 3$ pF, the parallel resonance frequency is $f_0 = 600$ MHz, and the circuit negative resistance $R_c = -100\Omega$. The frequency when $X_\alpha - X_c = 0$ on each characteristic curve is unwanted resonance frequency. From Figure 11, it is clear that the unwanted resonance frequency is present in the frequency lower than 600MHz. However, in the frequency of 480MHz or above, the oscillator cannot oscillate as is clear from Figure 10. In the frequency not higher than 400MHz, the negative resistance of the Colpitts oscillation circuit shown in Figure 25 does not occur, and therefore, the oscillator cannot oscillate.

Figure 12 illustrates a relationship between unwanted

resonance frequency and circuit capacitance. The ordinate represents unwanted resonance frequency, and the abscissa represents circuit capacitance. From Figure 12, it is clear that when C_c is 5pF or above, low frequency unwanted resonance
5 occurs in the frequency 400MHz or below, and high frequency unwanted resonance occurs in the frequency 580MHz or above.

As explained above, according to the circuit of the present invention shown in Figure 1, it is made clear by the simulation that the increase in the negative resistance and unwanted
10 oscillation can be prevented, by connecting the inductor L_0 to the parallel capacitance C_0 of the oscillator and by connecting proper resistance R_0 in parallel.

A frequency band in which unwanted resonance does not occur is obtained next.

15 This operation is the same as obtaining a range in which an absolute value $|R_c|$ of the negative resistance of the circuit is smaller than series resistance r_a .

Conditions for not generating unwanted resonance are obtained from the Exp. (10), the Exp. (4), and the Exp. (12).

$$\begin{aligned}
\frac{R_0 \times X_0^2}{R_0^2 + X_0^2} - R_c > 0 \quad \dots \quad X_0 &= \frac{1}{\omega C_0 \left(\frac{\omega_0^2}{\omega^2} - 1 \right)} \quad \dots \quad \frac{R_0}{R_c} > 0 \\
\frac{R_0 X_0^2}{R_0^2 + X_0^2} - R_c > 0 \quad \dots \quad \frac{1}{X_0^2} &< \frac{1}{R_0^2} \left(\frac{R_0}{R_c} - 1 \right) \\
\omega^2 C_0^2 \left(\frac{\omega_0^2}{\omega^2} - 1 \right)^2 &< \frac{1}{R_0^2} \left(\frac{R_0}{R_c} - 1 \right) \quad \dots \quad \omega^2 \left(\frac{\omega_0^2}{\omega^2} - 1 \right)^2 < \frac{1}{C_0^2 R_0^2} \left(\frac{R_0}{R_c} - 1 \right) \\
\Theta K &= \frac{M}{C_0^2 R_0^2}, \quad M = \left(\frac{R_0}{R_c} - 1 \right) \quad \dots \quad (15)
\end{aligned}$$

$$\omega^2 \left(\frac{\omega_0^2}{\omega^2} - 1 \right)^2 < K \quad \dots \quad \frac{\omega_0^4}{\omega^2} - 2\omega_0^2 + \omega^2 < K \quad \dots \quad \omega^4 - (2\omega_0^2 + K)\omega^2 + \omega_0^4 < 0 \quad \dots \quad (16)$$

$$f(\omega^2) = \omega^4 - (2\omega_0^2 + K)\omega^2 + \omega_0^4 \quad \dots \quad (17)$$

From the Exp. (17), a root is obtained by setting $f(\omega^2) = 0$.

$$\omega^2 = \omega_0^2 + \frac{K}{2} \pm \frac{\sqrt{K(K + 4\omega_0^2)}}{2} = \omega_0^2 + \frac{K \pm \sqrt{K(K + 4\omega_0^2)}}{2} \quad \dots \quad (18)$$

$$\omega_1^2 = \omega_0^2 + \frac{K - \sqrt{K(K + 4\omega_0^2)}}{2} \quad \dots \quad \omega_1 = \sqrt{\omega_0^2 + \frac{K - \sqrt{K(K + 4\omega_0^2)}}{2}} \quad \dots \quad (19)$$

$$\omega_2^2 = \omega_0^2 + \frac{K + \sqrt{K(K + 4\omega_0^2)}}{2} \quad \dots \quad \omega_2 = \sqrt{\omega_0^2 + \frac{K + \sqrt{K(K + 4\omega_0^2)}}{2}} \quad \dots \quad (20)$$

Exp. (21) is obtained when the unwanted resonance non-angular bandwidth is ω_T .

$$\omega_1 < \omega_T < \omega_2 \quad \dots \quad (21)$$

The bandwidth is obtained.

$$\omega_2^2 - \omega_1^2 = (\omega_2 - \omega_1)(\omega_2 + \omega_1) = \sqrt{K(K + 4\omega_0^2)}, \quad \omega_2 + \omega_1 = 2\omega_0 \quad (22)$$

From the Exp. (22), the bandwidth is set to $\Delta\omega T$, and Exp. (23) is obtained.

$$\Delta\omega_T = \omega_2 - \omega_1 = \frac{\sqrt{K(K + 4\omega_0^2)}}{2\omega_0} = \sqrt{\frac{K^2}{4\omega_0^2} + K} \quad (23)$$

Q when the parallel resonance frequency of $C_0/L_0/R_0$ is ω_0 is obtained from Exp. (24).

$$Q = \frac{R_0}{\omega_0 L_0} = \omega_0 C_0 R_0 \quad (24)$$

The Exp. (24) is substituted into Exp. (15) to obtain Exp. (25).

$$K = \frac{M}{C_0^2 R_0^2} = \frac{\omega_0^2 M}{Q^2}, \quad M = \frac{R_0}{R_c} - 1 \quad (25)$$

$$\begin{aligned} \Delta\omega_T &= \frac{1}{4\omega_0^2} \times \frac{\omega_0^4}{Q^4} M^2 + \frac{\omega_0^2}{Q^2} M = \frac{\omega_0^2}{Q^2} M \left\{ 1 + \frac{1}{4\omega_0^2} \times \frac{\omega_0^2}{Q^2} M \right\} \\ &= \frac{\omega_0^2}{Q^2} M \left\{ 1 + \frac{1}{4} \times \frac{1}{Q^2} M \right\} = \frac{\omega_0^2}{Q^2} M \frac{4Q^2 + M}{4Q^2} = \frac{\omega_0^2}{4Q^4} M \{4Q^2 + M\} \\ \Delta\omega_T &= \frac{\omega_0}{2Q^2} \sqrt{M(4Q^2 + M)} \quad (26) \end{aligned}$$

Exp. (26) shows the unwanted resonance non-angular bandwidth using Q.

Figure 13 is a circuit diagram of a high-frequency piezoelectric oscillator according to the first embodiment of the present invention. This high-frequency piezoelectric oscillator comprises an oscillation circuit 20 and an output circuit 30. The output circuit 30 is not a main portion of the

present invention, and therefore, its explanation will be omitted.

Only the oscillation circuit 20 will be explained. Capacitors C1 and C2 that become a part of the load capacitance are connected between the base of the transistor TR1 and the ground. The connection point of the capacitors C1 and C2 is connected to an emitter of the transistor TR1, and is grounded via the emitter resistance R1. A base bias circuit consisting of the resistor RB1 and the resistor RB2 is connected to the base of the transistor TR1. The piezoelectric vibrator (X'tal), the inductor L0, and the resistor R0 are connected in parallel, and the parallel circuit is connected between the base of the transistor TR1 and a capacitor C3. The capacitor C3 is grounded. Further, the collector of the transistor TR1 and the power supply line (Vcc) are connected.

In the present invention, the TR1 is MT4S101T, $C1 = 5\text{pF}$, $C2 = 8\text{pF}$, $C3 = 100\text{pF}$, $R1 = 180\Omega$, $RB1 = 10\text{K}\Omega$, and $RB2 = 22\text{K}\Omega$. As parameters of the piezoelectric vibrator (X'tal), the interelectrode capacitance of the oscillator is $C0 = 3.5\text{pF}$, and the capacitance ratio is $C0/C1 = 451$. Figure. rate merit that represents a good level of the oscillator is $M = 1.39$ (no oscillation occurs in the inductive region when $M < 2$). The parallel connection inductor $L0 = 22\text{nH}$, and $Q = 20$. Based on $Q = 20$, resistance that floats in the inductor is about 1500Ω , and the parallel connection resistance is $R0 = 470\Omega$. From this, the inductor parallel resistance becomes $1500\Omega // 470\Omega = 360\Omega$, and the resonance frequency of the oscillator X'tal becomes 600MHz .

Figure 14 is a waveform diagram of the oscillation circuit 20 according to the present invention. From Figure 14, it is clear that the frequency is stable in about 600MHz, and the waveform has small distortion.

5 Figure 15 illustrates power supply variation characteristics of the oscillation circuit 20 according to the present invention. From Figure 15, it is confirmed that no abnormal oscillation occurs due to variation in the power supply and frequency. It is also confirmed that the oscillation is
10 from the oscillator and is not unwanted oscillation, from the stable level of the oscillation (± 2 ppm @ $\pm 5\%$ VCC or below). Therefore, it is clear from the result that the oscillation is the oscillator oscillation.

Figure 16 illustrates a result of a simulation carried
15 out using the oscillation circuit 20 when the parallel capacitance of the oscillator is $C_0 = 3.5\text{pF}$, the parallel connection inductor is $L_0 = 22\text{nH}$, and the parallel connection resistance is $R_0 = 470\Omega$. From this result, it is clear that when the frequency is 620MHz, the conversion capacitance is C_α
20 $= 0.5\text{pF}$, the conversion resistance $r_\alpha = 240\Omega$, and the negative resistance is $R_L = -137\Omega$. In other words, it is clear that the present invention is a very effective method to solve the problem of the increase in the interelectrode capacitance of the oscillator and the reduction in the "Figure of Merit" when the
25 oscillator is in high frequency.

Figure 17 is a circuit diagram of a high-frequency piezoelectric oscillator according to the second embodiment of

the present invention. As like constituent elements are designated with like reference numerals, a redundant explanation will be omitted. The configuration shown in Figure 17 is different from that shown in Figure 1 in that a variable
5 capacitance diode D1 is inserted in series into the inductor L0, and peripheral circuits R2, R3, and C4 are added. With this arrangement, a voltage is applied to a V.CON terminal to make the capacitance of the inductor L0 variable, thereby to optimize the oscillation and make it possible to control frequency.

10 Figure 18 is a circuit diagram of a high-frequency piezoelectric oscillator according to the third embodiment of the present invention. As like constituent elements are designated with like reference numerals, a redundant explanation will be omitted. The configuration shown in Figure 18 is
15 different from that shown in Figure 1 in that the variable capacitance diode D1 and an inductor L1 is inserted in series into the capacitor C3, and the peripheral circuits R3 and C4 are added. With this arrangement, a voltage is applied to the V.CON terminal to make the capacitance of the inductor L0 variable,
20 thereby to optimize the oscillation and make it possible to control frequency.

While the present invention is explained above using the oscillation circuit having the fundamental frequency of the oscillator as the oscillation frequency, the present invention
25 is not limited to this arrangement. It is also possible to apply the invention to an oscillation circuit having overtone frequency of third order, fifth order, a seventh order, or a higher order

of the oscillator as oscillation frequency.

Figure 19 illustrates a relationship with the additional resistance R_0 , the load resistance R_L , and the unwanted resonance frequency when the oscillation frequency is 622MHz.

5 The negative resistance of the circuit is -160Ω , and the resistance R_0 to the parallel capacitance C_0 of the oscillator exceeds the absolute value of this negative resistance.

Therefore, an unwanted resonance non-angular bandwidth occurs.

A maximum bandwidth of about 170MHz is obtained at about 300Ω .

10 The negative resistance of a series arm of the piezoelectric vibrator consisting of the $C_1/L_1/R_1$ decreases when the circuit capacitance becomes smaller, and has a maximum value when the R_0 is between 200Ω and 300Ω . This value becomes about -500Ω which is about three times the negative resistance -160Ω of
15 the circuit, when $C_c = 50\text{pF}$.

Figure 20 illustrates a relationship with Q at the parallel resonance of $C_0/L_0/R_0$, the load resistance R_L , and the unwanted resonance bandwidth, where the Q changes by changing the resistance R_0 . The parallel resonance frequency $f_0 = 600\text{MHz}$.

20 The negative resistance of the series arm shows a maximum value when Q is between 2 and 3, and the unwanted resonance bandwidth shows a maximum value when Q is between 3 and 4. The bandwidth naturally becomes smaller when Q becomes larger.

Figure 21 illustrates a relationship between the negative
25 resistance of the series arm and the unwanted resonance bandwidth when the additional resistance is fixed to $R_0 = 200\Omega$ and when the negative resistance of the circuit is variable.

The negative resistance of the series arm falls rapidly and the unwanted resonance bandwidth becomes larger when the negative resistance of the circuit becomes smaller. Particularly, the unwanted resonance bandwidth spreads large
5 to the high frequency side.

As explained above, the negative resistance of the series arm of the oscillator can be made larger when the inductor and the resistor of proper resistance are added to the parallel capacitance of the oscillator. At the same time, unwanted
10 resonance can be suppressed by adding the inductor. When the piezoelectric vibrator is used for the oscillator, the electrode that excites the vibrator cannot be removed from the vibrator. The vibrator becomes thinner when the frequency becomes higher. Therefore, the interelectrode capacitance increases. This is
15 a crucial problem of the piezoelectric vibrator. To overcome the problem, the interelectrode capacitance (i.e., parallel capacitance) of the vibrator can be cancelled or bad influence can be minimized by adding the resistor of proper resistance in the present invention. In other words, it is anticipated
20 that the future piezoelectric oscillator can be adapted to higher frequency. As a result, the invention can greatly contribute to the device or system that uses the piezoelectric vibrator.

As explained above, according to the first aspect of the present invention, a resistor and an inductor, those values are
25 proper respectively, are connected in parallel to the piezoelectric vibrator. Therefore, the interelectrode capacitance due to the high-frequency piezoelectric oscillation

can be decreased, and oscillation due to unwanted resonance can be suppressed. Consequently, high stability can be obtained.

According to the second aspect of the present invention, a variable capacitance diode is connected in series to the
5 inductor. Therefore, the capacitance of the inductor can be made variable by externally applying a voltage. Consequently, the oscillation can be optimized, and frequency can be controlled.

According to the third aspect of the present invention,
10 a variable capacitance diode is connected in series to a parallel resonance circuit. Therefore, the capacitance of the inductor can be made variable by externally applying a voltage. Consequently, the oscillation can be optimized, and frequency can be controlled.

15 According to the fourth aspect of the present invention, a proper equivalent circuit can accurately determine proper additional resistance and inductance based on oscillation frequency.

According to the fifth and sixth aspects of the present
20 invention, an inductor and a resistor of proper resistance are added to the parallel capacitance of the oscillator. Therefore, the negative resistance of the series arm of the oscillator can be increased, and unwanted resonance due to the addition of the inductor can be restricted.

25